

TLV2241, TLV2242, TLV2244 FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

- **Micropower Operation . . . 1 μ A/Channel**
- **Rail-to-Rail Input/Output**
- **Gain Bandwidth Product . . . 5.5 kHz**
- **Supply Voltage Range . . . 2.5 V to 12 V**
- **Specified Temperature Range**
 - $T_A = 0^\circ\text{C}$ to 70°C . . . **Commercial Grade**
 - $T_A = -40^\circ\text{C}$ to 125°C . . . **Industrial Grade**
- **Ultrasmall Packaging**
 - **5-Pin SOT-23 (TLV2241)**
 - **8-Pin MSOP (TLV2242)**
- **Universal OpAmp EVM**

description

The TLV224x family of single-supply operational amplifiers offers very low supply current of only 1 μ A per channel.

The low supply current is coupled with extremely low input bias currents enabling them to be used with mega- Ω resistors making them ideal for portable, long active life, applications. DC accuracy is ensured with a low typical offset voltage as low as 600 μ V, CMRR of 100 dB, and minimum open loop gain of 100 V/mV at 2.7 V.

The maximum recommended supply voltage is as high as 12 V and ensured operation down to 2.5 V, with electrical characteristics specified at 2.7 V, 5 V and 12 V. The 2.5-V operation makes it compatible with Li-Ion battery-powered systems and many micropower microcontrollers available today including TI's MSP430.

Operational Amplifier



SUPPLY CURRENT
vs
SUPPLY VOLTAGE



FAMILY PACKAGE TABLE

DEVICE	NO. OF Ch	PACKAGE TYPES					UNIVERSAL EVM
		PDIP	SOIC	SOT-23	TSSOP	MSOP	
TLV2241	1	8	8	5	—	—	Refer to the EVM Selection Guide (Lit# SLOU060)
TLV2242	2	8	8	—	—	8	
TLV2244	4	14	14	—	14	—	

SELECTION OF SINGLE SUPPLY OPERATIONAL AMPLIFIER PRODUCTS†

DEVICE	V _{DD} (V)	V _{IO} (mV)	BW (MHz)	SLEW RATE (V/ μ s)	I _{DD} (PER CHANNEL) (μ A)	RAIL-TO-RAIL
TLV240x‡	2.5–16	0.390	0.005	0.002	0.880	I/O
TLV224x	2.5–12	0.600	0.005	0.002	1	I/O
TLV2211	2.7–10	0.450	0.065	0.025	13	O
TLV245x	2.7–6	0.020	0.22	0.110	23	I/O
TLV225x	2.7–8	0.200	0.2	0.12	35	O

† All specifications are typical values measured at 5 V.

‡ This device also offers 18-V reverse battery protection and 5-V over-the-rail operation on the inputs.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS
INSTRUMENTS**

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TLV2241 AVAILABLE OPTIONS

T _A	V _{IOmax} AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE† (D)	SOT-23‡ (DBV)	SYMBOLS	PLASTIC DIP (P)
0°C to 70°C	3000 μ V	TLV2241CD	—	—	—
-40°C to 125°C		TLV2241ID	TLV2241DBV	VBEI	TLV2241IP

† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2241CDR).

‡ This package is available in a 250 piece mini-reel. To order this package, add a T suffix to the part number (e.g., TLV2241DBVT). This package is also available in a 3000 piece reel, add a R suffix to the part number (e.g., TLV2241DBVR).

TLV2242 AVAILABLE OPTIONS

T _A	V _{IOmax} AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE† (D)	MSOP† (DGK)	SYMBOLS	PLASTIC DIP (P)
0°C to 70°C	3000 μ V	TLV2242CD	—	—	—
-40°C to 125°C		TLV2242ID	TLV2242IDGK	xxTIALE	TLV2242IP

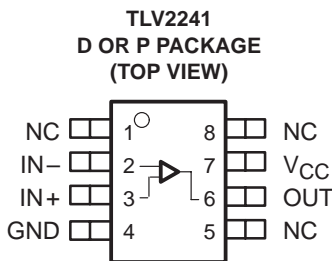
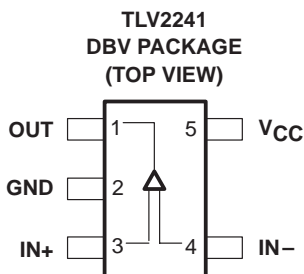
† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2242CDR).

TLV2244 AVAILABLE OPTIONS

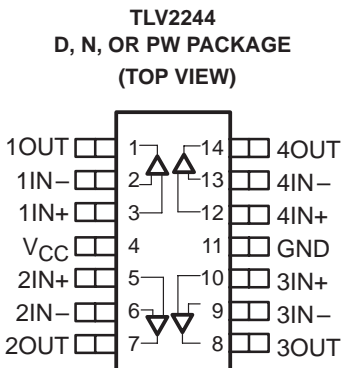
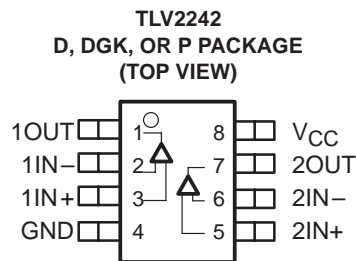
T _A	V _{IOmax} AT 25°C	PACKAGED DEVICES		
		SMALL OUTLINE† (D)	PLASTIC DIP (N)	TSSOP (PW)
0°C to 70°C	3000 μ V	TLV2244CD	—	—
-40°C to 125°C		TLV2244ID	TLV2244IN	TLV2244IPW

† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2244CDR).

TLV224x PACKAGE PINOUTS



NC – No internal connection



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} (see Note 1)	16.5 V
Differential input voltage, V_{ID}	$\pm V_{CC}$
Input current, I_I (any input)	± 10 mA
Output current, I_O	± 10 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	–40°C to 125°C
Maximum junction temperature, T_J	150°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential voltages, are with respect to GND

DISSIPATION RATING TABLE

PACKAGE	Θ_{JC} (°C/W)	Θ_{JA} (°C/W)	$T_A \leq 25^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D (8)	38.3	176	710 mW	142 mW
D (14)	26.9	122.6	1022 mW	204.4 mW
DBV (5)	55	324.1	385 mW	77.1 mW
DGK (8)	54.2	259.9	481 mW	96.2 mW
N (14)	32	78	1600 mW	320.5 mW
P (8)	41	104	1200 mW	240.4 mW
PW (14)	29.3	173.6	720 mW	144 mW

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{CC}	Single supply	2.5	12	V
	Split supply	± 1.25	± 6	
Common-mode input voltage range, V_{ICR}		0	V_{CC}	V
Operating free-air temperature, T_A	C-suffix	0	70	°C
	I-suffix	–40	125	

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electrical characteristics at recommended operating conditions, $V_{CC} = 2.7, 5 \text{ V}$, and 12 V (unless otherwise noted)†‡

dc performance

PARAMETER		TEST CONDITIONS	T_A †	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_O = V_{CC}/2 \text{ V}$, $V_{IC} = V_{CC}/2 \text{ V}$, $R_S = 50 \Omega$	25°C	600	3000		μV
			Full range		4500		
αV_{IO}	Offset voltage drift		25°C	3			$\mu\text{V}/^\circ\text{C}$
CMRR	Common-mode rejection ratio	$V_{IC} = 0 \text{ to } V_{CC}$, $R_S = 50 \Omega$	$V_{CC} = 2.7 \text{ V}$	25°C	55	100	dB
				Full range	50		
			$V_{CC} = 5 \text{ V}$	25°C	60	100	
				Full range	53		
			$V_{CC} = 12 \text{ V}$	25°C	60	100	
				Full range	55		
AVD	Large-signal differential voltage amplification	$V_{CC} = 2.7 \text{ V}$, $V_{O(pp)} = 1 \text{ V}$, $R_L = 500 \text{ k}\Omega$	25°C	100	400	V/mV	
			Full range	30			
			$V_{CC} = 5 \text{ V}$, $V_{O(pp)} = 3 \text{ V}$, $R_L = 500 \text{ k}\Omega$	25°C	250		1000
				Full range	100		
			$V_{CC} = 12 \text{ V}$, $V_{O(pp)} = 6 \text{ V}$, $R_L = 500 \text{ k}\Omega$	25°C	700		1500
				Full range	120		

† Full range is 0°C to 70°C for the C suffix and –40°C to 125°C for the I suffix. If not specified, full range is –40°C to 125°C.

input characteristics

PARAMETER		TEST CONDITIONS	T_A †	MIN	TYP	MAX	UNIT	
I_{IO}	Input offset current	$V_O = V_{CC}/2 \text{ V}$, $V_{IC} = V_{CC}/2 \text{ V}$, $R_S = 50 \Omega$	25°C	25	250		pA	
			Full range	TLV224xC		300		
				TLV224xI		400		
I_{IB}	Input bias current	$V_O = V_{CC}/2 \text{ V}$, $V_{IC} = V_{CC}/2 \text{ V}$, $R_S = 50 \Omega$	25°C	100	500		pA	
			Full range	TLV224xC		550		
				TLV224xI		1000		
$r_{i(d)}$	Differential input resistance		25°C	300			$\text{M}\Omega$	
$C_{i(c)}$	Common-mode input capacitance	$f = 100 \text{ kHz}$	25°C	3			pF	

† Full range is 0°C to 70°C for the C suffix and –40°C to 125°C for the I suffix. If not specified, full range is –40°C to 125°C.

‡ Specifications at 5 V are ensured by design and device testing at 2.7 V and 12 V.



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electrical characteristics at recommended operating conditions, $V_{CC} = 2.7, 5 \text{ V}$, and 12 V (unless otherwise noted)[†] (continued)

output characteristics

PARAMETER	TEST CONDITIONS	T_A [†]	MIN	TYP	MAX	UNIT
V_{OH} High-level output voltage	$V_{IC} = V_{CC}/2$, $I_{OH} = -2 \mu\text{A}$	$V_{CC} = 2.7 \text{ V}$	25°C	2.65	2.68	V
			Full range	2.63		
		$V_{CC} = 5 \text{ V}$	25°C	4.95	4.98	
			Full range	4.93		
		$V_{CC} = 12 \text{ V}$	25°C	11.95	11.98	
			Full range	11.93		
	$V_{IC} = V_{CC}/2$, $I_{OH} = -50 \mu\text{A}$	$V_{CC} = 2.7 \text{ V}$	25°C	2.62	2.65	
			Full range	2.6		
		$V_{CC} = 5 \text{ V}$	25°C	4.92	4.95	
			Full range	4.9		
		$V_{CC} = 12 \text{ V}$	25°C	11.92	11.95	
			Full range	11.9		
V_{OL} Low-level output voltage	$V_{IC} = V_{CC}/2$, $I_{OL} = 2 \mu\text{A}$	25°C		90	150	mV
		Full range			180	
	$V_{IC} = V_{CC}/2$, $I_{OL} = 50 \mu\text{A}$	25°C		180	230	
		Full range			260	
I_O Output current	$V_O = 0.5 \text{ V}$ from rail	25°C		± 200		μA

[†] Full range is 0°C to 70°C for the C suffix and -40°C to 125°C for the I suffix. If not specified, full range is -40°C to 125°C.

power supply

PARAMETER	TEST CONDITIONS	T_A [†]	MIN	TYP	MAX	UNIT
I_{CC} Supply current (per channel)	$V_O = V_{CC}/2$	$V_{CC} = 2.7 \text{ V}$ or 5 V	25°C	980	1200	nA
			Full range		1500	
		$V_{CC} = 12 \text{ V}$	25°C	1000	1250	
			Full range		1550	
PSRR Power supply rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$V_{CC} = 2.7$ to 5 V , $V_{IC} = V_{CC}/2 \text{ V}$, No load,	TLV224xC	25°C	70	100	dB
			Full range	65		dB
		TLV224xI	25°C	60		dB
	$V_{CC} = 5$ to 12 V , $V_{IC} = V_{CC}/2 \text{ V}$, No load	25°C	70	100	dB	
		Full range	70		dB	

[†] Full range is 0°C to 70°C for the C suffix and -40°C to 125°C for the I suffix. If not specified, full range is -40°C to 125°C.

[‡] Specifications at 5 V are ensured by design and device testing at 2.7 V and 12 V.



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electrical characteristics at recommended operating conditions, $V_{CC} = 2.7, 5 \text{ V}$, and 12 V (unless otherwise noted)† (continued)

dynamic performance

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP	MAX	UNIT		
UGBW	Unity gain bandwidth	$R_L = 500 \text{ k}\Omega$,	$C_L = 100 \text{ pF}$	25°C		5.5		kHz		
SR	Slew rate at unity gain	$V_{O(pp)} = 0.8 \text{ V}$,	$R_L = 500 \text{ k}\Omega$, $C_L = 100 \text{ pF}$	25°C		2		V/ms		
ϕM	Phase margin	$R_L = 500 \text{ k}\Omega$, $C_L = 100 \text{ pF}$		25°C				60		
	Gain margin							15	dB	
t_s	Settling time	$V_{CC} = 2.7 \text{ or } 5 \text{ V}$, $V(\text{STEP})_{PP} = 1 \text{ V}$, $A_V = -1$,	$C_L = 100 \text{ pF}$, $R_L = 100 \text{ k}\Omega$	25°C				1.84	ms	
								0.1%		6.1
			$V_{CC} = 12 \text{ V}$, $V(\text{STEP})_{PP} = 1 \text{ V}$, $A_V = -1$,					$C_L = 100 \text{ pF}$, $R_L = 100 \text{ k}\Omega$		0.01%

noise/distortion performance

PARAMETER		TEST CONDITIONS	T_A	MIN	TYP	MAX	UNIT	
V_n	Equivalent input noise voltage	$f = 10 \text{ Hz}$	25°C				800	$\text{nV}/\sqrt{\text{Hz}}$
		$f = 100 \text{ Hz}$					500	
I_n	Equivalent input noise current	$f = 100 \text{ Hz}$					8	$\text{fA}/\sqrt{\text{Hz}}$

† Specifications at 5 V are ensured by design and device testing at 2.7 V and 12 V.



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TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	vs Common-mode input voltage	1, 2, 3
I_{IB}	Input bias current	vs Free-air temperature	4, 6, 8
		vs Common-mode input voltage	5, 7, 9
I_{IO}	Input offset current	vs Free-air temperature	4, 6, 8
		vs Common-mode input voltage	5, 7, 9
CMRR	Common-mode rejection ratio	vs Frequency	10
V_{OH}	High-level output voltage	vs High-level output current	11, 13, 15
V_{OL}	Low-level output voltage	vs Low-level output current	12, 14, 16
$V_{O(PP)}$	Output voltage peak-to-peak	vs Frequency	17
Z_o	Output impedance	vs Frequency	18
I_{CC}	Supply current	vs Supply voltage	19
PSRR	Power supply rejection ratio	vs Frequency	20
A_{VD}	Differential voltage gain	vs Frequency	21
	Phase	vs Frequency	21
	Gain-bandwidth product	vs Supply voltage	22
SR	Slew rate	vs Free-air temperature	23
ϕ_m	Phase margin	vs Capacitive load	24
	Gain margin	vs Capacitive load	25
	Voltage noise over a 10 Second Period		26
	Large-signal voltage follower		27, 28, 29
	Small-signal voltage follower		30
	Large-signal inverting pulse response		31, 32, 33
	Small-signal inverting pulse response		34
	Crosstalk	vs Frequency	35

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TYPICAL CHARACTERISTICS

**INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT
VOLTAGE**

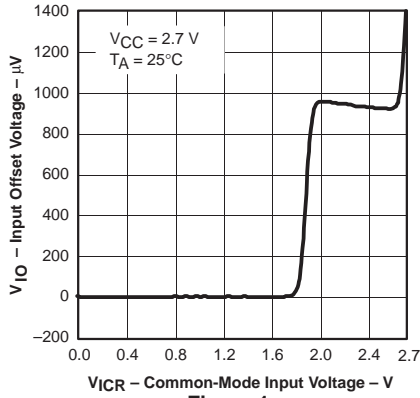


Figure 1

**INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT
VOLTAGE**

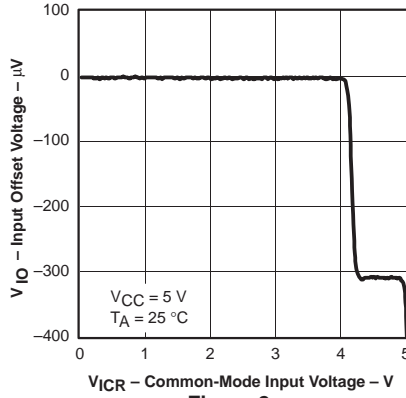


Figure 2

**INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT
VOLTAGE**

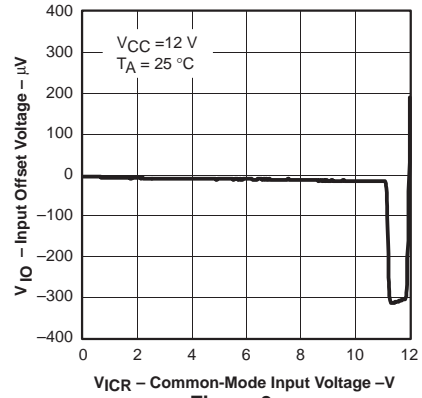


Figure 3

**INPUT BIAS / OFFSET CURRENT
vs
FREE-AIR TEMPERATURE**



Figure 4

**INPUT BIAS / OFFSET CURRENT
vs
COMMON MODE INPUT
VOLTAGE**



Figure 5

**INPUT BIAS / OFFSET CURRENT
vs
FREE-AIR TEMPERATURE**



Figure 6

**INPUT BIAS / OFFSET CURRENT
vs
COMMON-MODE INPUT
VOLTAGE**

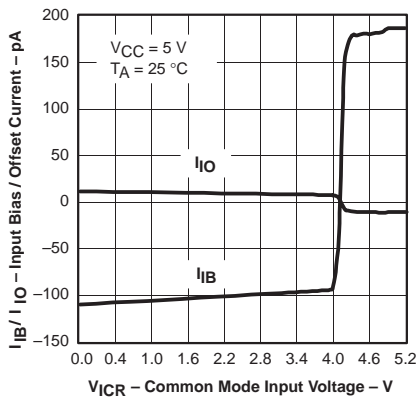


Figure 7

**INPUT BIAS / OFFSET CURRENT
vs
FREE-AIR TEMPERATURE**

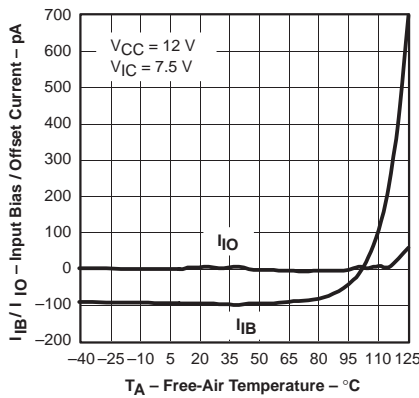


Figure 8

**INPUT BIAS / OFFSET CURRENT
vs
COMMON-MODE INPUT
VOLTAGE**

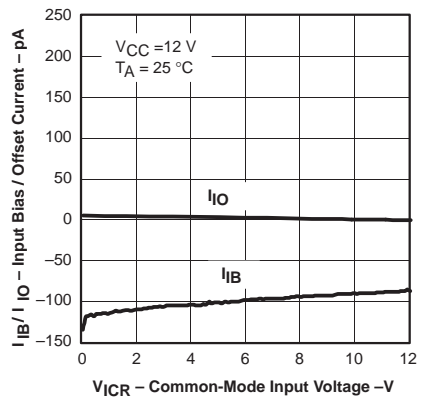


Figure 9



TYPICAL CHARACTERISTICS

COMMON-MODE REJECTION RATIO
 vs
 FREQUENCY



Figure 10

HIGH-LEVEL OUTPUT VOLTAGE
 vs
 HIGH-LEVEL OUTPUT CURRENT



Figure 11

LOW-LEVEL OUTPUT VOLTAGE
 vs
 LOW-LEVEL OUTPUT CURRENT



Figure 12

HIGH-LEVEL OUTPUT VOLTAGE
 vs
 HIGH-LEVEL OUTPUT CURRENT

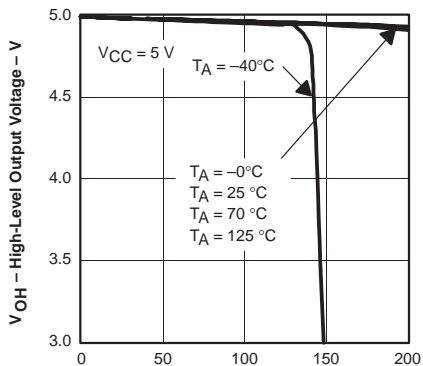


Figure 13

LOW-LEVEL OUTPUT VOLTAGE
 vs
 LOW-LEVEL OUTPUT CURRENT



Figure 14

HIGH-LEVEL OUTPUT VOLTAGE
 vs
 HIGH-LEVEL OUTPUT CURRENT



Figure 15

LOW-LEVEL OUTPUT VOLTAGE
 vs
 LOW-LEVEL OUTPUT CURRENT

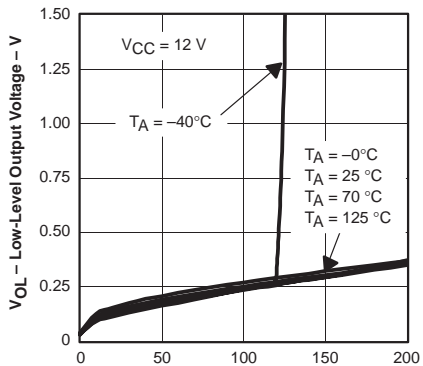


Figure 16

OUTPUT VOLTAGE
 PEAK-TO-PEAK
 vs
 FREQUENCY

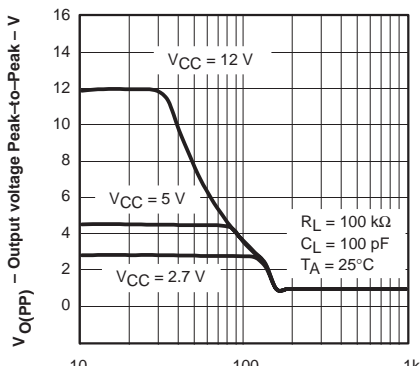


Figure 17

OUTPUT IMPEDANCE
 vs
 FREQUENCY

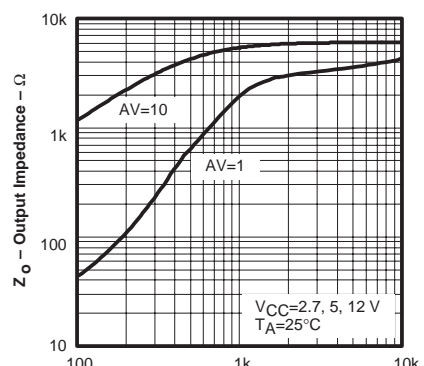
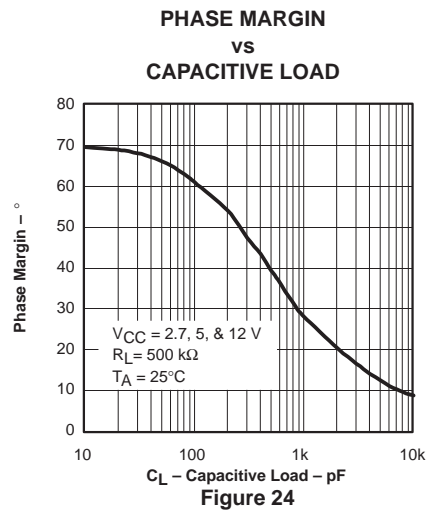
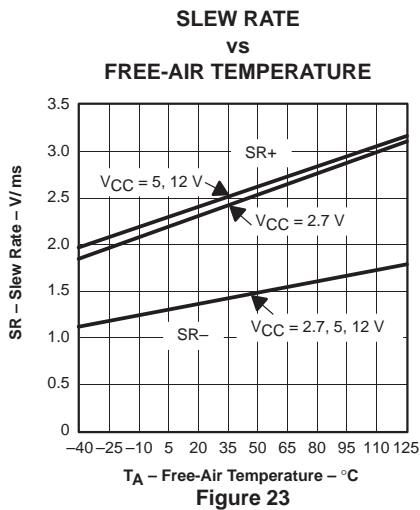
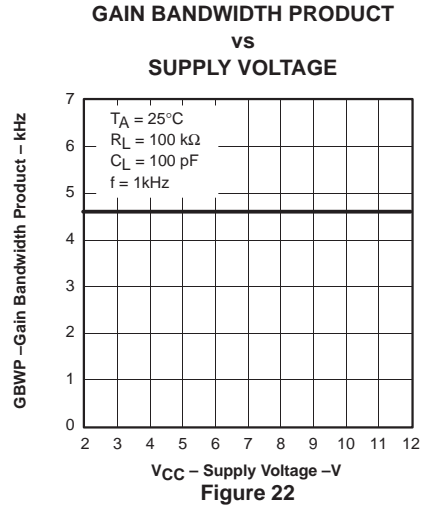
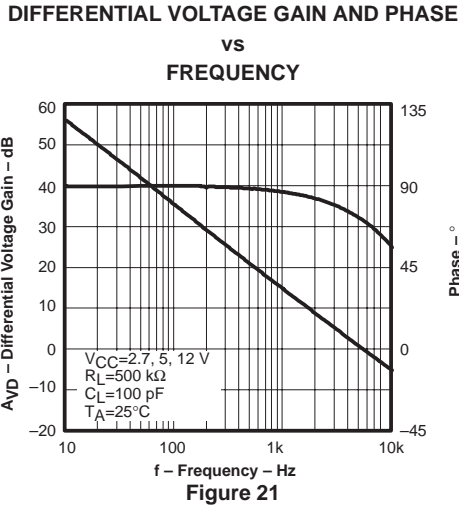
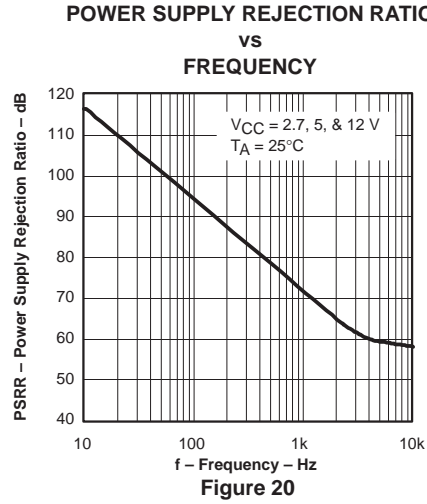
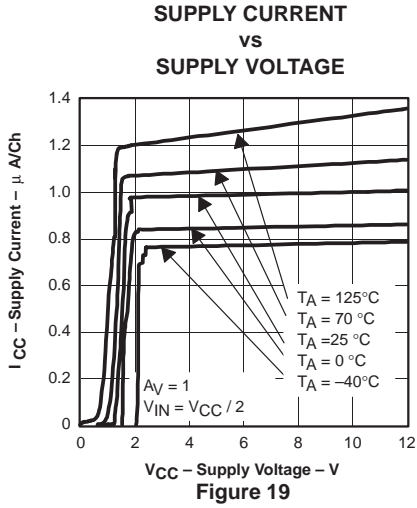


Figure 18

TLV2241, TLV2242, TLV2244 FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

GAIN MARGIN
 VS
 CAPACITIVE LOAD

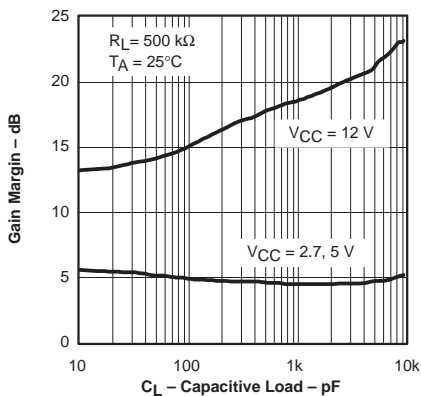


Figure 25

VOLTAGE NOISE
 OVER A 10 SECOND PERIOD

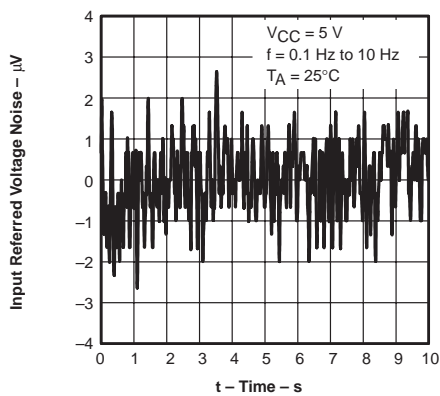


Figure 26

LARGE SIGNAL FOLLOWER
 PULSE RESPONSE

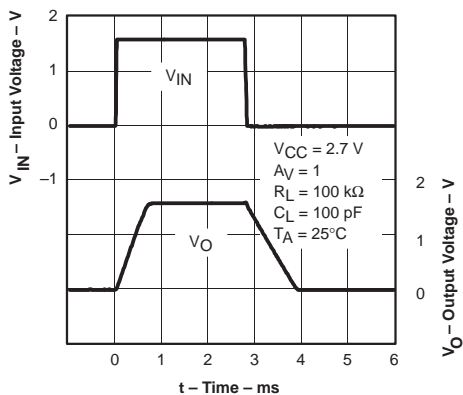


Figure 27

LARGE SIGNAL FOLLOWER
 PULSE RESPONSE

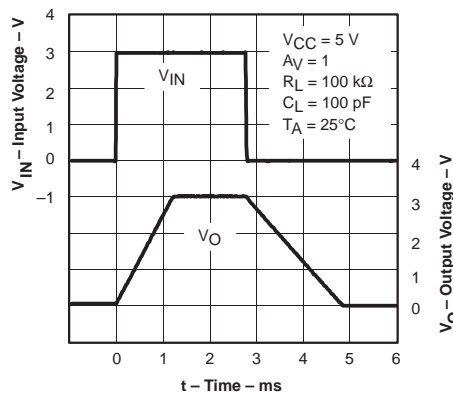


Figure 28

LARGE SIGNAL FOLLOWER
 PULSE RESPONSE



Figure 29

SMALL SIGNAL FOLLOWER
 PULSE RESPONSE

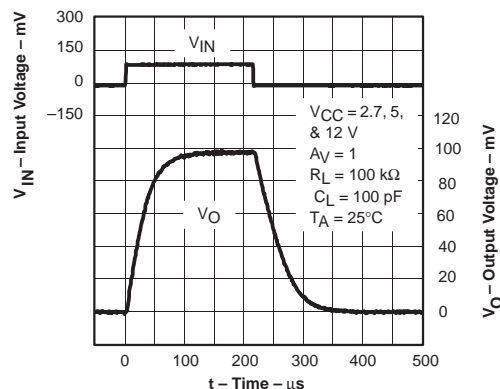


Figure 30

TLV2241, TLV2242, TLV2244 FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS

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TYPICAL CHARACTERISTICS

**LARGE SIGNAL INVERTING
PULSE RESPONSE**

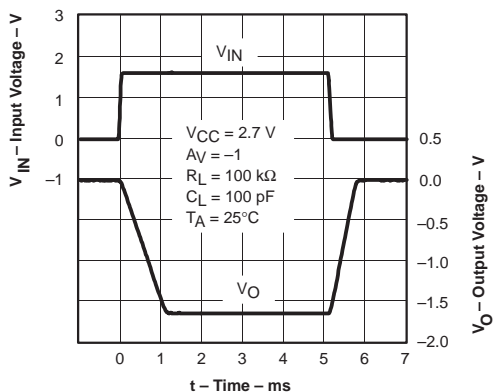


Figure 31

**LARGE SIGNAL INVERTING
PULSE RESPONSE**

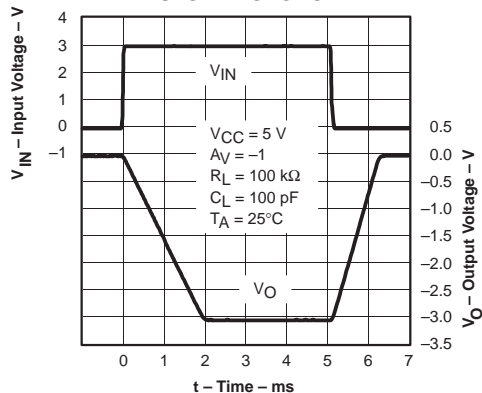


Figure 32

**LARGE SIGNAL INVERTING
PULSE RESPONSE**

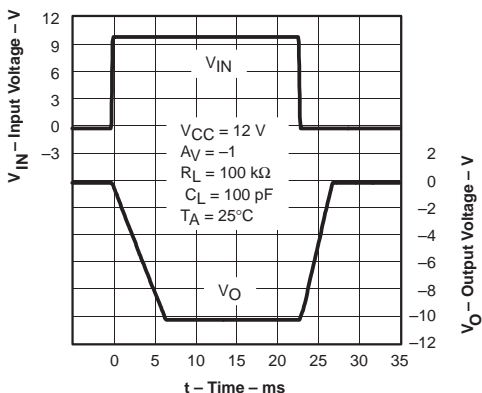


Figure 33

**SMALL SIGNAL INVERTING
PULSE RESPONSE**

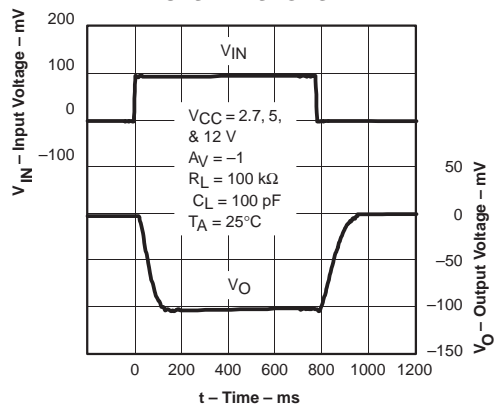


Figure 34

CROSTALK vs FREQUENCY

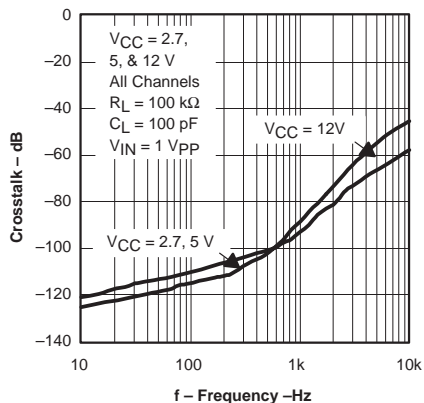


Figure 35



APPLICATION INFORMATION

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:



$$V_{OO} = V_{IO} \left(1 + \left(\frac{R_F}{R_G} \right) \right) \pm I_{IB+} R_S \left(1 + \left(\frac{R_F}{R_G} \right) \right) \pm I_{IB-} R_F$$

Figure 36. Output Offset Voltage Model

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 37).

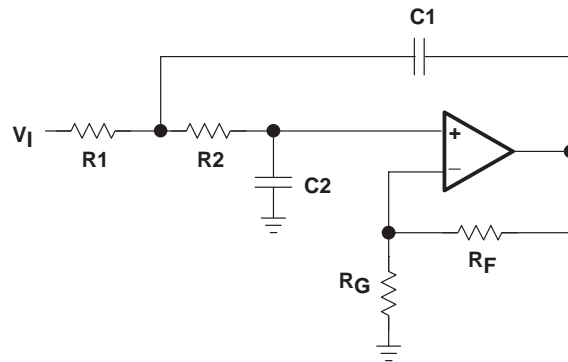


$$f_{-3dB} = \frac{1}{2\pi R1 C1}$$

$$\frac{V_O}{V_I} = \left(1 + \frac{R_F}{R_G} \right) \left(\frac{1}{1 + sR1C1} \right)$$

Figure 37. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.



$R1 = R2 = R$
 $C1 = C2 = C$
 $Q = \text{Peaking Factor}$
 (Butterworth $Q = 0.707$)

$$f_{-3dB} = \frac{1}{2\pi RC}$$

$$R_G = \frac{R_F}{\left(2 - \frac{1}{Q} \right)}$$

Figure 38. 2-Pole Low-Pass Sallen-Key Filter

APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV224x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes—It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling—Use a 6.8- μ F tantalum capacitor in parallel with a 0.1- μ F ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- μ F ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μ F capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets—Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements—Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components—Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

APPLICATION INFORMATION

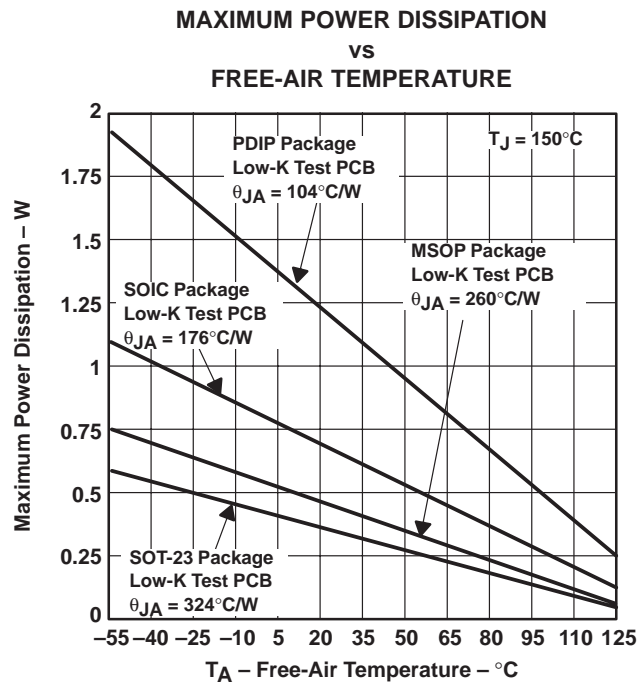
general power dissipation considerations

For a given θ_{JA} , the maximum power dissipation is shown in Figure 39 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

- P_D = Maximum power dissipation of THS224x IC (watts)
- T_{MAX} = Absolute maximum junction temperature (150°C)
- T_A = Free-ambient air temperature (°C)
- θ_{JA} = $\theta_{JC} + \theta_{CA}$
- θ_{JC} = Thermal coefficient from junction to case
- θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 39. Maximum Power Dissipation vs Free-Air Temperature

TLV2241, TLV2242, TLV2244 FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS

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APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™ Release 8, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 2) and subcircuit in Figure 40 are generated using the TLV224x typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 2: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

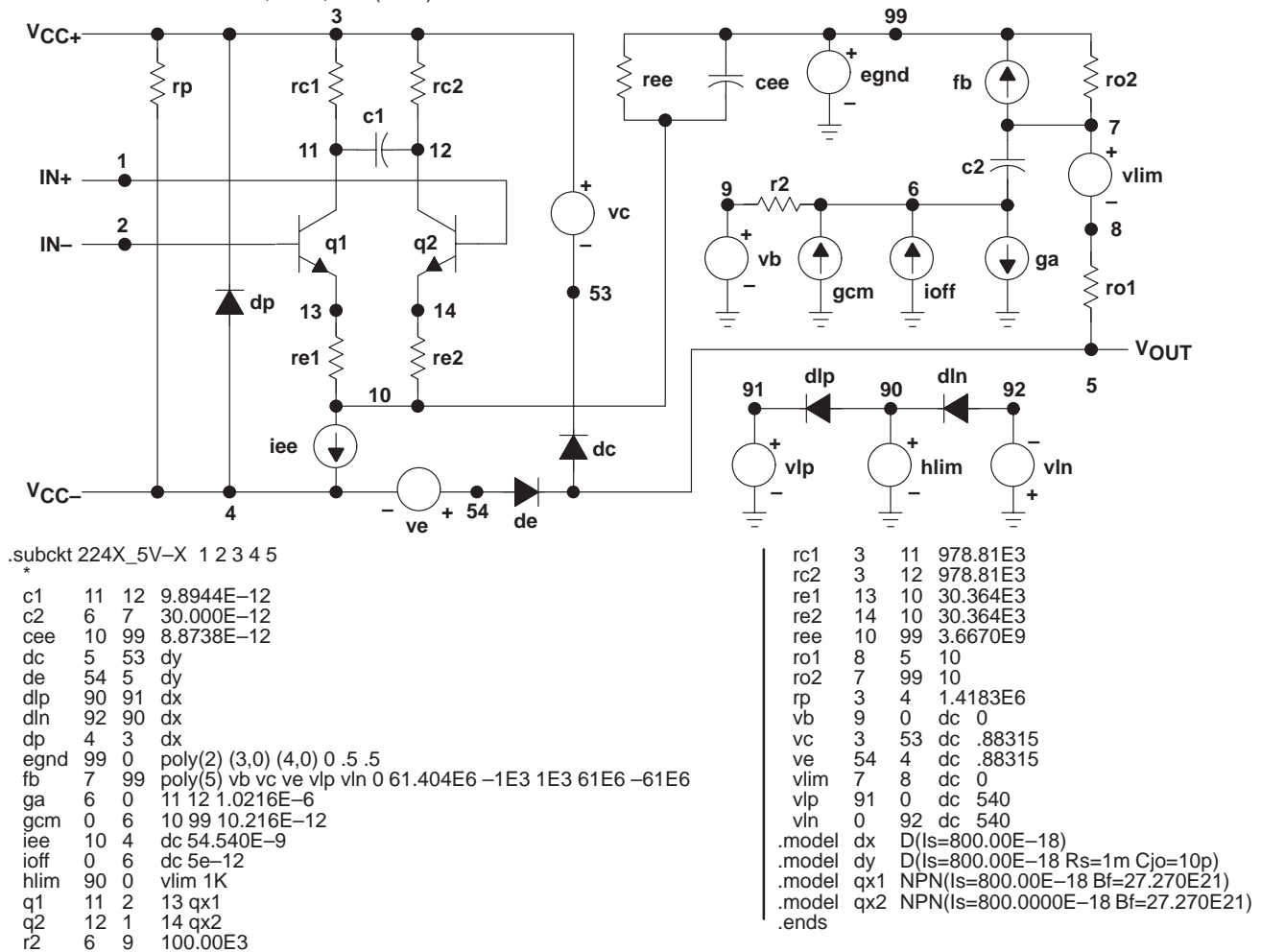


Figure 40. Boyle Macromodels and Subcircuit

PSpice and *Parts* are trademarks of MicroSim Corporation.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2241ID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	2241I
TLV2241IDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	VBEI
TLV2241IDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	VBEI
TLV2241IDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	VBEI
TLV2241IDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBEI
TLV2241IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2241I
TLV2241IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2241I
TLV2241IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2241I
TLV2241IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2241I
TLV2242CD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2242C
TLV2242CD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2242C
TLV2242CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2242C
TLV2242CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2242C
TLV2242ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2242I
TLV2242ID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2242I
TLV2242IDGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALE
TLV2242IDGK.A	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALE
TLV2242IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALE
TLV2242IDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALE
TLV2242IDGKRG4	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLV2242IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2242I
TLV2242IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2242I
TLV2242IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2242I
TLV2242IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2242I
TLV2244ID	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2244I
TLV2244ID.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2244I
TLV2244IDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2244I
TLV2244IDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2244I
TLV2244IPW	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2244I

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2244IPW.A	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2244I
TLV2244IPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2244I
TLV2244IPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2244I

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

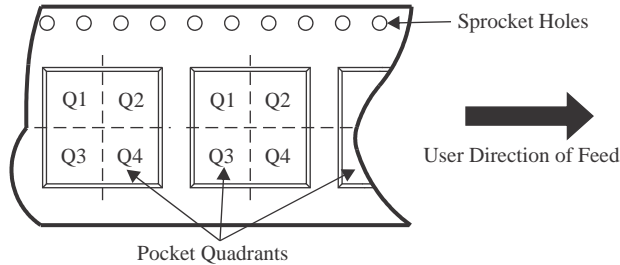
(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2241IDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2241IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2241IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2242CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2242IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2242IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2244IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2244IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2241IDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
TLV2241IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TLV2241IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2242CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2242IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2242IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2244IDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2244IPWR	TSSOP	PW	14	2000	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLV2241IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2241IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2242CD	D	SOIC	8	75	507	8	3940	4.32
TLV2242CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2242CD.A	D	SOIC	8	75	507	8	3940	4.32
TLV2242CD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2242ID	D	SOIC	8	75	507	8	3940	4.32
TLV2242ID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2242ID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2242ID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2242IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2242IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2244ID	D	SOIC	14	50	505.46	6.76	3810	4
TLV2244ID.A	D	SOIC	14	50	505.46	6.76	3810	4
TLV2244IPW	PW	TSSOP	14	90	530	10.2	3600	3.5
TLV2244IPW.A	PW	TSSOP	14	90	530	10.2	3600	3.5

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

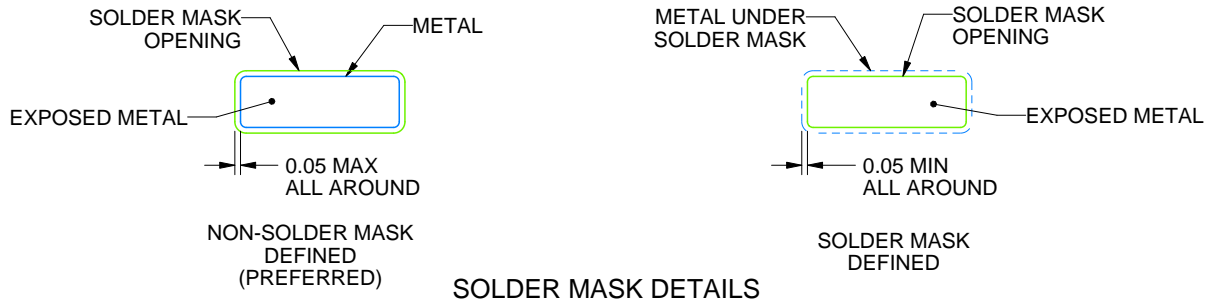
DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.



D0014A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

EXAMPLE BOARD LAYOUT

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
 EXPOSED METAL SHOWN
 SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.



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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



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NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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